# Hex D Master/Slave Flip-Flop

The MC10176 contains six high-speed, master slave type "D" flip-flops. Clocking is common to all six flip-flops. Data is entered into the master when the clock is low. Master to slave data transfer takes place on the positive-going Clock transition. Thus, outputs may change only on a positive-going Clock transition. A change in the information present at the data (D) input will not affect the output information any other time due to the master-slave construction of this device.

- $P_D = 460 \text{ mW typ/pkg (No Load)}$
- $f_{toggle} = 150 \text{ MHz (typ)}$
- $t_r$ ,  $t_f = 2.0$  ns typ (20%-80%)

# **LOGIC DIAGRAM** D0 Q0 D1 Q1 6 D2 Q2 D3 10 13 Q3 D4 11 Q4 V<sub>CC1</sub> = PIN 1 V<sub>CC2</sub> = PIN 16 VEE = PIN 8 15 Q5 CLOCK

### **CLOCKED TRUTH TABLE**

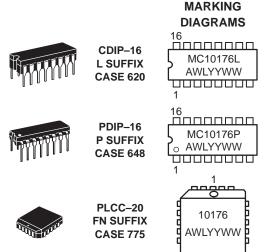
С	D	Q <sub>n+1</sub>
L	Х	Q <sub>n</sub>
H*	L	L
H*	Н	Н

\*A clock H is a clock transition from a low to a high state.



# ON Semiconductor

http://onsemi.com



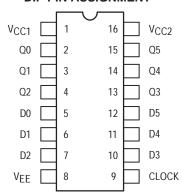
= Assembly Location

WL = Wafer Lot

YY = Year

WW = Work Week

# **DIP PIN ASSIGNMENT**



Pin assignment is for Dual-in-Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).

### **ORDERING INFORMATION**

_		_
Device	Package	Shipping
MC10176L	CDIP-16	25 Units / Rail
MC10176P	PDIP-16	25 Units / Rail
MC10176FN	PLCC-20	46 Units / Rail

# **ELECTRICAL CHARACTERISTICS**

			Test Limits							
		Pin Under Test	-30°C		+25°C		+85°C		1	
Characteristic	Symbol		Min	Max	Min	Тур	Max	Min	Max	Unit
Power Supply Drain Current	ΙE	8		121		88	110		121	mAdc
Input Current	l <sub>inH</sub>	5 9		350 495			220 310		220 310	μAdc
	l <sub>inL</sub>	5 9	0.5 0.5		0.5 0.5			0.3 0.3		μAdc
Output Voltage Logic 1	Vон	2† 15†	-1.060 -1.060	-0.890 -0.890	-0.960 -0.960		-0.810 -0.810	-0.890 -0.890	-0.700 -0.700	Vdc
Output Voltage Logic 0	VOL	2† 15†	-1.890 -1.890	-1.675 -1.675	-1.850 -1.850		-1.650 -1.650	-1.825 -1.825	-1.615 -1.615	Vdc
Threshold Voltage Logic 1	Vона	2† 15†	-1.080 -1.080		-0.980 -0.980			-0.910 -0.910		Vdc
Threshold Voltage Logic 0	VOLA	2† 15†		-1.655 -1.655			-1.630 -1.630		-1.595 -1.595	Vdc
Switching Times (50 $\Omega$ Load) Clock Input										ns
Propagation Delay	t9+2+ t9+2-	2 2	1.6 1.6	4.6 4.6	1.6 1.6		4.5 4.5	1.6 1.6	5.0 5.0	
Rise Time (20 to 80%)	t <sub>2+</sub>	2	1.0	4.1	1.1		4.0	1.1	4.4	
Fall Time (20 to 80%)	t <sub>2</sub> _	2	1.0	4.1	1.1		4.0	1.1	4.4	
Setup Time	t <sub>setup</sub>	2	2.5		2.5			2.5		ns
Hold Time	thold	2	1.5		1.5			1.5		ns
Toggle Frequency (Max)	f <sub>tog</sub>	2	125		125	150		125		MHz

<sup>†</sup>Output level to be measured after a clock pulse has been applied to the C Input (Pin 9) VILmin

# **ELECTRICAL CHARACTERISTICS** (continued)

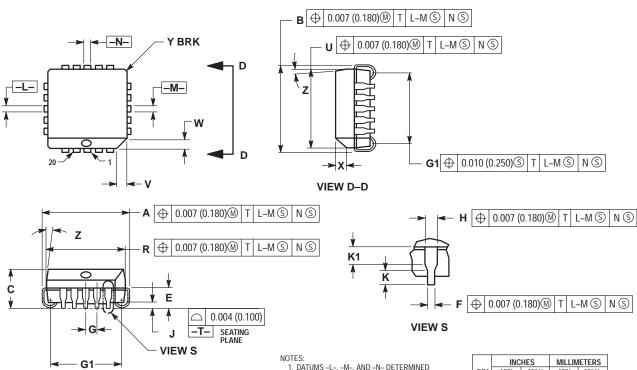
					TEST VO	LTAGE VALU	JES (Volts)		
		@ Test Te	mperature	V <sub>IHmax</sub>	V <sub>ILmin</sub>	VIHAmin	V <sub>ILAmax</sub>	VEE	]
			–30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
			Pin	TEST VOLTAGE APPLIED TO PINS LISTED BELOW				BELOW	()()
Characteristic		Symbol	Under Test	V <sub>IHmax</sub>	V <sub>ILmin</sub>	VIHAmin	V <sub>ILAmax</sub>	VEE	(VCC)
Power Supply Drain Current		ΙΕ	8					8	1, 16
Input Current		l <sub>inH</sub>	5 9	5 9				8 8	1, 16 1, 16
		linL	5 9		5 9			8 8	1, 16 1, 16
Output Voltage L	ogic 1	VOH	2† 15†	5 12				8 8	1, 16 1, 16
Output Voltage L	.ogic 0	VOL	2† 15†		5 12			8 8	1, 16 1, 16
Threshold Voltage L	.ogic 1	Vона	2† 15†			5 12		8 8	1, 16 1, 16
Threshold Voltage L	.ogic 0	VOLA	2† 15†				5 12	8 8	1, 16 1, 16
Switching Times (50Ω	Load)			+1.11Vdc	+0.31V	Pulse In	Pulse Out	-3.2 V	+2.0 V
Clock Input Propagation	Delay	t <sub>9+2+</sub> t <sub>9+2-</sub>	2 2			5, 9 5, 9	2 2	8 8	1, 16 1, 16
Rise Time (20 to	80%)	t <sub>2+</sub>	2			5, 9	2	8	1, 16
Fall Time (20 to	80%)	t <sub>2-</sub>	2			5, 9	2	8	1, 16
Setup Time		t <sub>setup</sub>	2			5, 9	2	8	1, 16
Hold Time		thold	2			5, 9	2	8	1, 16
Toggle Frequency (Max)		f <sub>tog</sub>	2					8	1, 16

<sup>†</sup> Output level to be measured after a clock pulse has been applied to the C Input (Pin 9)

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to -2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

### PACKAGE DIMENSIONS

### PLCC-20 **FN SUFFIX** PLASTIC PLCC PACKAGE CASE 775-02 **ISSUE C**



⊕ 0.010 (0.250)⑤ T L-M ⑤ N ⑤

- WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
- 2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

  3. DIMENSIONS R AND U DO NOT INCLUDE MOLD.
- FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.

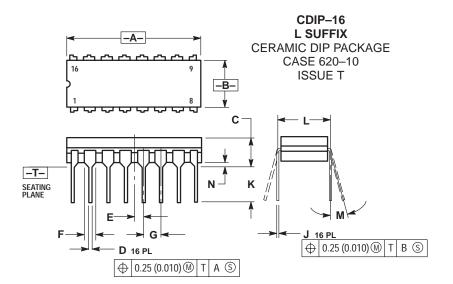
  4. DIMENSIONING AND TOLERANCING PER ANSI

- 4. DIMENSIONING AND TOLERANCING FER ANSI Y14.5M, 1982. 5. CONTROLLING DIMENSION: INCH. 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300).
  DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP
- INCLUDING ANY MISMAICH BE I WEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

  7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.385	0.395	9.78	10.03	
В	0.385	0.395	9.78	10.03	
С	0.165	0.180	4.20	4.57	
Ε	0.090	0.110	2.29	2.79	
F	0.013	0.019	0.33	0.48	
G	0.050	BSC	1.27	BSC	
Н	0.026	0.032	0.66	0.81	
J	0.020		0.51		
K	0.025		0.64		
R	0.350	0.356	8.89	9.04	
U	0.350	0.356	8.89	9.04	
٧	0.042	0.048	1.07	1.21	
W	0.042	0.048	1.07	1.21	
Х	0.042	0.056	1.07	1.42	
Υ		0.020		0.50	
Z	2°	10°	2°	10 °	
G1	0.310	0.330	7.88	8.38	
K1	0.040		1.02		

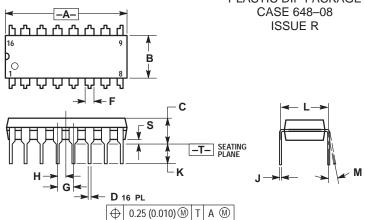
# **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
  4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INC	HES	MILLIN	IETERS		
DIM	MIN MAX		MIN	MAX		
Α	0.750	0.785	19.05	19.93		
В	0.240	0.295	6.10	7.49		
С		0.200		5.08		
D	0.015	0.020	0.39	0.50		
E	0.050	) BSC	1.27 BSC			
F	0.055	0.065	1.40	1.65		
G	0.100	BSC	2.54 BSC			
Н	0.008	0.015	0.21	0.38		
K	0.125	0.170	3.18	4.31		
L	0.300	BSC	7.62	BSC		
M	0°	15°	0 °	15°		
N	0.020	0.040	0.51	1.01		

# PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS		
DIM	MIN MAX		MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10 °	0 °	10 °	
S	0.020	0.040	0.51	1.01	

# **Notes**

# **Notes**

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